



HER2001 thru HER2007

High Efficient Rectifiers
Reverse Voltage 50 to 1000 Volts Forward Current 2.0 Amperes

Features

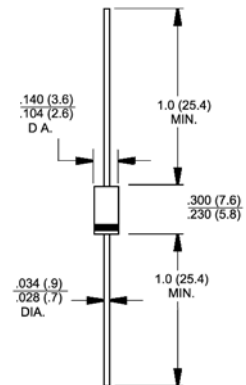
- ◆ Low cost
- ◆ Diffused junction
- ◆ Ultra fast switching for high efficiency
- ◆ Low reverse leakage current
- ◆ Low forward voltage drop
- ◆ High current capability
- ◆ The plastic material carries UL recognition 94V-0
- ◆ T_J is 150°C (Max.) and T_{STG} is 175°C (Max.) with PI glue



DO-204AC (DO-15)

Mechanical Data

- ◆ Case : JEDEC DO-204AC(DO-15) molded plastic
- ◆ Polarity : Color band denotes cathode
- ◆ Weight : 0.014 ounce, 0.39 gram
- ◆ Mounting position : Any



Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

| Parameter | Symbols | HER 2001 | HER 2002 | HER 2003 | HER 2004 | HER 2005 | HER 2006 | HER 2007 | Units |
|---|-----------------|----------|----------|----------|----------|-------------|----------|----------|--------------------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | Volts |
| Maximum RMS voltage | V_{RMS} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | Volts |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | Volts |
| Maximum average forward rectified current @ $T_A=55^\circ\text{C}$ | $I_{(AV)}$ | | | | | 2.0 | | | Amps |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | I_{FSM} | | | | | 60.0 | | | Amps |
| Maximum forward voltage at 2.0A DC | V_F | 1.0 | | | 1.3 | | 1.7 | | Volts |
| Maximum DC reverse current at rated DC blocking voltage @ $T_J=25^\circ\text{C}$ @ $T_J=100^\circ\text{C}$ | I_R | | | | | 5.0 | | | μA |
| | | | | | | | | 100 | μA |
| Maximum reverse recovery time (Note 1) | t_{tr} | | | | 50 | | 75 | | nS |
| Typical junction capacitance (Note 2) | C_J | | | | 50 | | 30 | | pF |
| Typical thermal resistance (Note 3) | $R_{\theta JA}$ | | | | | 25 | | | $^\circ\text{C/W}$ |
| Operating junction temperature range | T_J | | | | | -55 to +125 | | | $^\circ\text{C}$ |
| Storage temperature range | T_{STG} | | | | | -55 to +150 | | | $^\circ\text{C}$ |

- Notes:**
1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{RR}=0.25\text{A}$.
 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 3. Thermal Resistance Junction to Ambient.

RATINGS AND CHARACTERISTIC CURVES

FIG.1 - FORWARD CURRENT DERATING CURVE

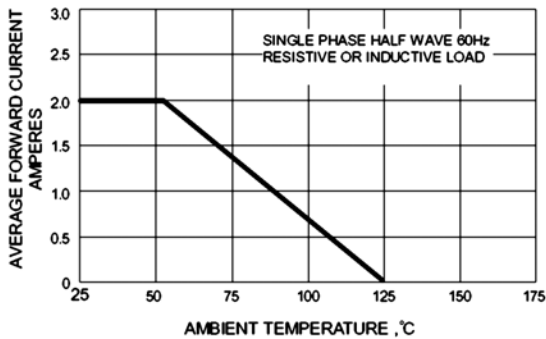


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

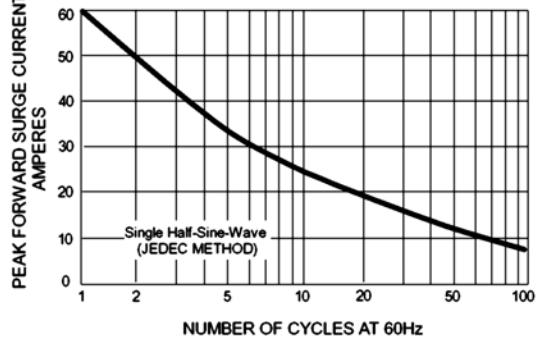


FIG.3 - TYPICAL JUNCTION CAPACITANCE

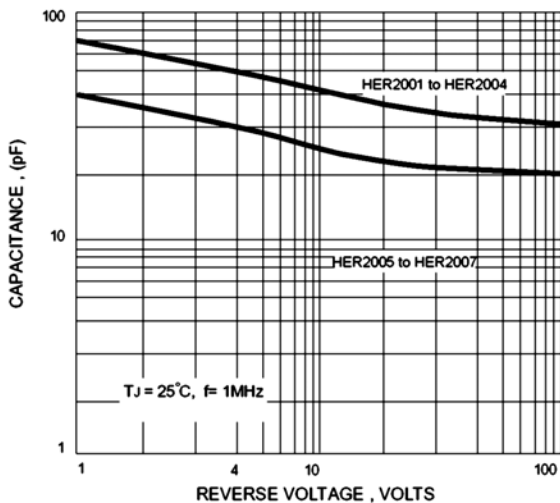


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

